OPB315 Series

• Opaque black plastic • 850 nm wavelength • Choice of leads or wires

Electronics OPB315L OPB315WZ

Description:

Features: • Lateral package

Each slotted optical switch in this series consists of an infrared emitting diode (LED) and a NPN silicon phototransistor mounted on opposite sides of a 0.90" (22.9 mm) wide slot in an opaque black plastic package.

The OPB315L has 0.25" minimum leads, while the OPB315WZ has a minimum of 24" (610 mm) 26 AWG wires.

Phototransistor switching takes place whenever an opaque object passes through the slot.

Applications:

- Non-contact object sensing
- Assembly line automation
- Machine automation
- Equipment security
- Machine safety



OPB315L

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0 (⊕ NOTES: PIN 2____ CATHODE PIN 4 EMITTER TOLERANCES ARE ± 0.010 [0.254] UNLESS OTHERWISE SPECIFIED. DIMENSIONS ARE IN: [MILLIMETERS] INCHES RoHS

General Note

TT Electronics reserves the right to make changes in product specification without notice or liability. All information is subject to TT Electronics' own data and is considered accurate at time of going to print.

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OPB315 Series



OPB315WZ







NOTES: 1. TOLERANCES ARE ± 0.010 UNLESS OTHERWISE SPECIFIED.

DIMENSIONS ARE IN: [MILLIMETERS] INCHES

OPB315WZ



Green

Pin #/ Color	LED	Pin #/ Color	Transistor	
Black	Cathode	White	Collector	
Red	Anode	Green	Emitter	

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OPB315 Series



Electrical Specifications

Absolute Maximum Ratings (T _A = 25° C unless otherwise noted)				
Storage Temperature Range	-40° C to +80° C			
Operating Temperature Range	-40° C to +80° C			
Reverse Voltage	2.0 V			
Continuous Forward Current	50 mA			
Peak Forward Current [measured at 1 μ s pulse width and 300 pps]	1.0 A			
Lead Soldering Temperature [1/16 inch (1.6 mm) from case for 5 seconds with soldering iron]	260° C ⁽¹⁾⁽²⁾			
Power Dissipation (Input Diode)	100 mW			
Power Dissipation (Output Phototransistor)	100 mW			

Electrical Characteristics (T _A = 25° C unless otherwise noted)							
SYMBOL	PARAMETER	MIN	ТҮР	MAX	UNITS	TEST CONDITIONS	
Input Diode							
V _F	Forward Voltage	-	1.4	1.7	V	I _F = 20 mA	
I _R	Reverse Current	-	-	100	μΑ	V _R =2 V	
Output Phototransistor (see OP550 for additional information)							
V _{(BR)(CEO)}	Collector-Emitter Breakdown Voltage	30	-	-	V	I _{CE} = 100 μA, I _F = 0 mA	
V _{(BR)(ECO)}	Emitter-Collector Breakdown Voltage	5.0	-	-	V	$I_{EC} = 100 \ \mu A$, $I_F = 0 \ mA$, $E_E = 0$	
I _{CEO}	Collector-Emitter Leakage Current	-	-	100	nA	$V_{CE} = 10.0 \text{ V}, I_F = 0 \text{ mA}, E_E = 0$	
Coupled							
I _{C(ON)}	On-State Collector Current	0.5	1.0	-	mA	$V_{CE} = 0.4 \text{ V}, I_F = 20 \text{ mA}$	
V _{CE(SAT)}	Collector-Emitter	-	-	0.4	V	$I_{c} = 500 \ \mu\text{A}, I_{F} = 20 \ \text{mA}$	

Notes:

1. RMA flux is recommended. Duration can be extended to 10 seconds maximum when flow soldering.

2. Derate linearly 1.33 mW/° C above 25° C.

OPB315 Series



OPB315



Forward Voltage vs Forward Current vs

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